

R-C Thermal Model Parameters

DESCRIPTION

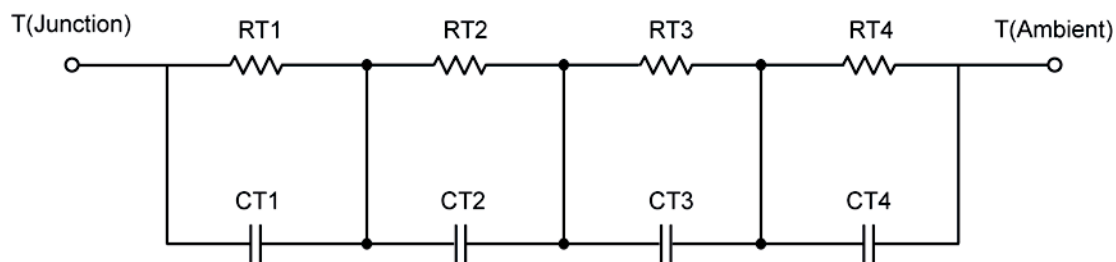
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

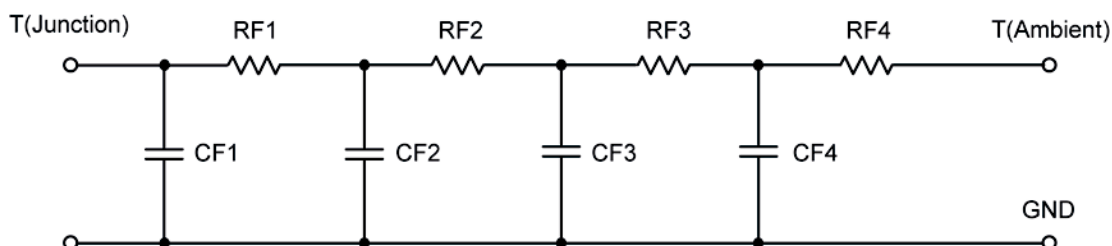
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



| R-C VALUES FOR TANK CONFIGURATION | | | |
|--|------------|------|------------|
| Thermal Resistance (°C/W) | | | |
| Junction to | Ambient | Case | Foot |
| RT1 | 214.2990 | N/A | 79.6144 |
| RT2 | 24.5623 | N/A | 15.9707 |
| RT3 | 98.8378 | N/A | 116.5748 |
| RT4 | 90.8922 | N/A | 124.3247 |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CT1 | 5.4751 m | N/A | 853.1305 u |
| CT2 | 230.4432 u | N/A | 121.8111 u |
| CT3 | 547.9173 m | N/A | 10.5289 m |
| CT4 | 1.1544 m | N/A | 3.6906 m |

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

| Thermal Resistance ($^{\circ}\text{C}/\text{W}$) | | | |
|--|----------------|------|----------------|
| Junction to | Ambient | Case | Foot |
| RF1 | 33.8048 | N/A | 21.3981 |
| RF2 | 107.4276 | N/A | 135.9713 |
| RF3 | 190.3794 | N/A | 84.0886 |
| RF4 | 96.8608 | N/A | 95.2982 |
| Thermal Capacitance (Joules/ $^{\circ}\text{C}$) | | | |
| Junction to | Ambient | Case | Foot |
| CF1 | 185.7535 μ | N/A | 95.6622 μ |
| CF2 | 704.7275 μ | N/A | 596.9559 μ |
| CF3 | 4.5727 m | N/A | 2.8977 m |
| CF4 | 506.5133 m | N/A | 3.9614 m |

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

